

900V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

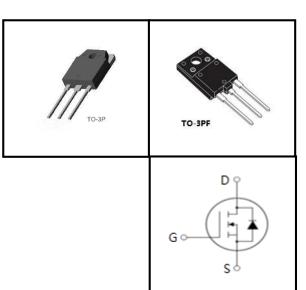
APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

Device Marking and Package Information				
Device	Package Marking			
CS11N90V	TO-3P CS11N90			
CS11N90VF	TO-3PF	CS11N90VF		

Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted					
Deservator	Gumbal	Value			
Parameter	Symbol	TO-3P	TO-3PF	Unit	
Drain-Source Voltage ($V_{GS} = 0V$)	V _{DSS}	900		V	
Continuous Drain Current	I _D	11		A	
Pulsed Drain Current (note1)	I _{DM}	44		А	
Gate-Source Voltage	V _{GSS}	±30		V	
Single Pulse Avalanche Energy (note2)	E _{AS}	520.2		mJ	
Avalanche Current (note1)	I _{AS}	10.2		A	
Repetitive Avalanche Energy (note1)	E _{AR}	312.1		mJ	
Power Dissipation ($T_c = 25^{\circ}C$)	P _D		70	w	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150		°C	

Thermal Resistance				
Deservator	Symbol	Value		
Parameter		TO-3P	TO-3PF	Unit
Thermal Resistance, Junction-to-Case	R _{thJC}	2		
Thermal Resistance, Junction-to-Ambient	R _{thJA}	50		K/W





CS11N90V, CS11N90VF

Devenedar			Value			
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	900			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 900V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.0		4.0	V
Drain-Source On-Resistance (Note3)	R _{DS(on)}	V _{GS} = 10V, I _D =5.5A		0.75	0.96	Ω
Dynamic						
Input Capacitance	C _{iss}	V _{GS} = 0V,		2571		
Output Capacitance	C _{oss}	$V_{DS} = 25V,$		244		pF
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		46		
Total Gate Charge	Q _g			107		
Gate-Source Charge	Q_gs	$V_{DD} = 720V, I_D = 11A, V_{GS} = 10V$		11.6		nC
Gate-Drain Charge	Q_{gd}			58.6		
Turn-on Delay Time	t _{d(on)}			54		
Turn-on Rise Time	t _r	V _{DD} = 450V, I _D = 11A,		44		
Turn-off Delay Time	t _{d(off)}	$R_{\rm G} = 25 \Omega$		444		ns
Turn-off Fall Time	t _f			86		
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I _s	T - 25.9C			11	٨
Pulsed Diode Forward Current	I _{SM}	T _C = 25 °C			44	A
Body Diode Voltage	V_{SD}	$T_J = 25^{o}C, I_{SD} = 5.5A, V_{GS} = 0V$			1.4	V
Reverse Recovery Time	t _{rr}	V _{GS} = 0V,I _S = 11A,		530		ns
Reverse Recovery Charge	Q _{rr}	di _F /dt =100A /µs		2.4		μC

Notes

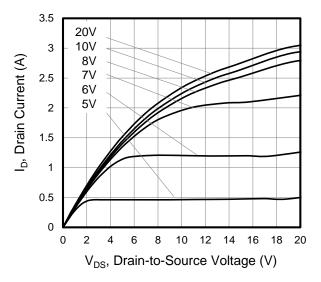
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=10mH, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25 °C
- 3. Pulse Test: Pulse width \leq 300µs, Duty Cycle \leq 1%



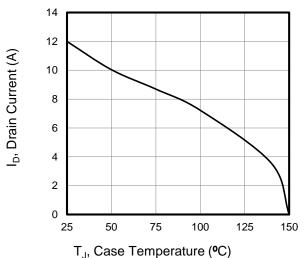
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^{\circ}C$)

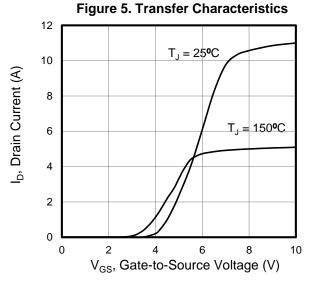












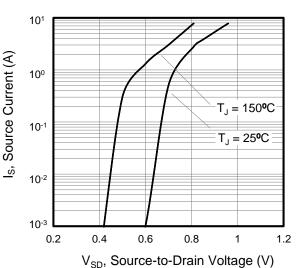
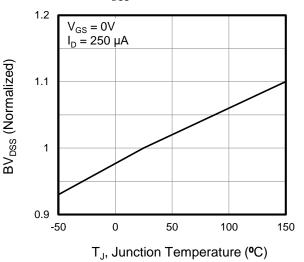
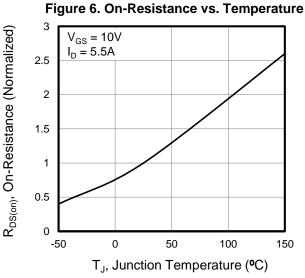


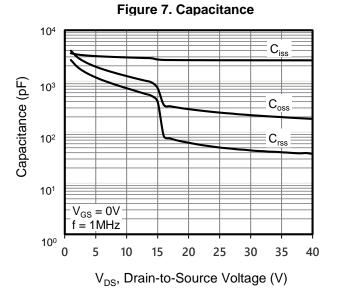
Figure 4. BV_{DSS} Variation vs. Temperature



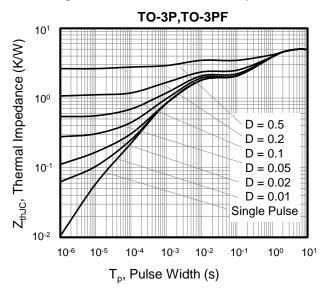


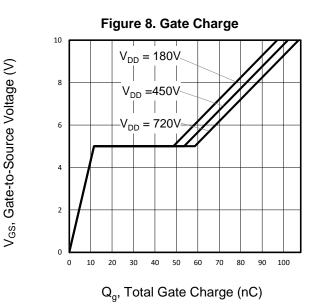


Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted













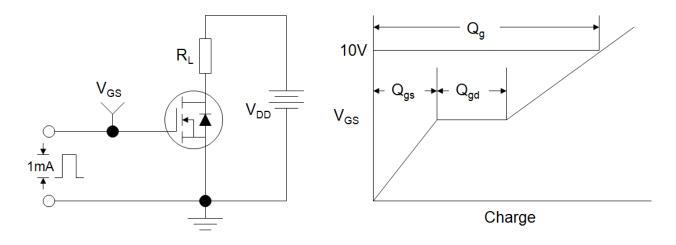


Figure B: Resistive Switching Test Circuit and Waveform

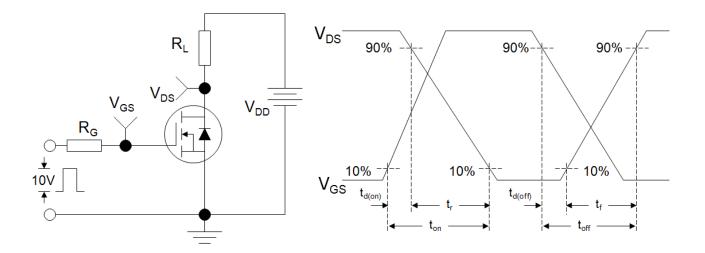
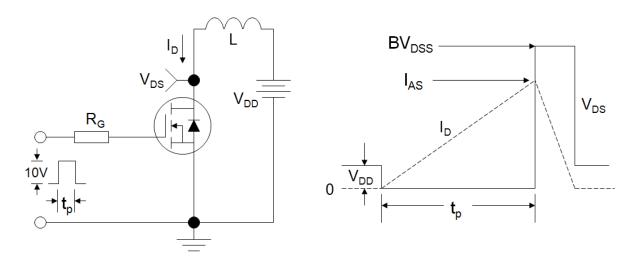


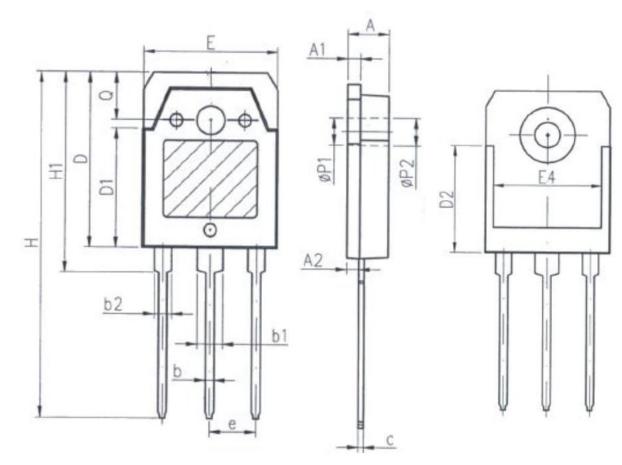
Figure C: Unclamped Inductive Switching Test Circuit and Waveform





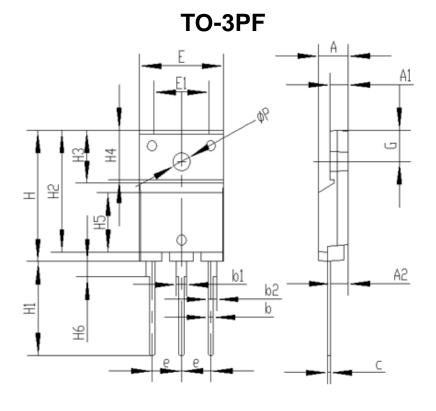


TO-3P



Unit:mm			
Symbol	Min.	Max.	
Α	4.6	5	
A1	1.4	1.65	
A2	1.18	1.58	
b	0.8	1.2	
b 1	2.8	3.2	
b2	1.8	2.2	
с	0.5	0.75	
D	19.6	20. 2	
D1	13.55	14. 25	
D2	12. 9	PREF	
E	15.35	15.85	
E4	12.6	-	
е	5. 45TYP		
Н	40.1	40.9	
H1	23.15	23.65	
P1	3. 2REF		
P2	3. 5REF		





-		(-)
1	2	3

Cumbal	单位 mm		
Symbol	Min	Nom	Max
Α	5.30	5.50	5.70
A1	3.30	3.50	3.70
A2	3.20	3.40	3.60
b	0.80	1.0	1.20
b1	1.80	2.00	2.20
b 2	1.40	1.60	1.80
С	0.40	0.50	0.60
е	5.25	5.45	5.65
E	15.4	15.6	15.8
E1	10.0	10.2	10.4
Н	22.8	23.0	23. 2
H1	16.0	16.5	17.0
H2	21.2	21.4	21.6
H3	9.10	9.30	9.50
H4	8.55	8.75	8.95
H5	10.2	10.4	10.6
H6	2.55	2.70	2.85
G	5.3	5.5	5.7
ΦΡ	3.00	3.20	3.40



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